

CentralTM Semiconductor Corp.

145 Adams Ave., Hauppauge, NY 11788 USA

Phone (631) 435-1110 FAX (631) 435-1824

Manufacturers of World Class Discrete Semiconductors

www.centrasemi.com

1N3595

SILICON LOW LEAKAGE DIODE

JEDEC DO-35 CASE

DESCRIPTION

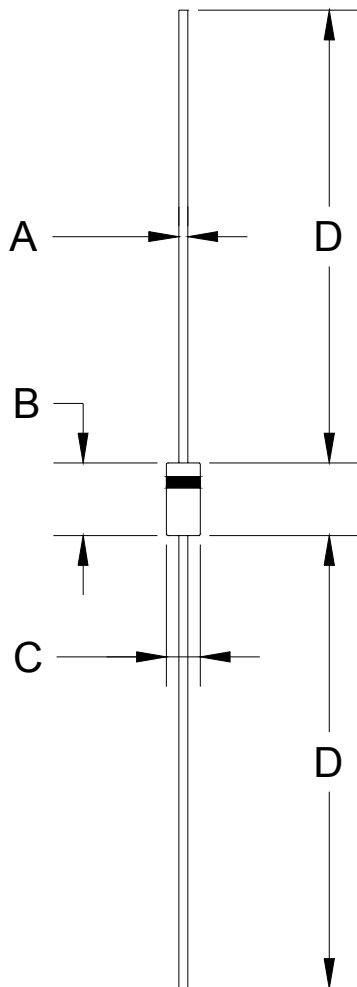
The CENTRAL SEMICONDUCTOR 1N3595 is an epitaxial planar silicon diode designed for low leakage, high conductance applications. Higher breakdown voltage devices are available on special order.

MAXIMUM RATINGS: ($T_A=25^{\circ}\text{C}$)

	<u>SYMBOL</u>		<u>UNITS</u>
Peak Repetitive Reverse Voltage	V_{RRM}	150	V
Peak Working Reverse Voltage	V_{RWM}	125	V
Average Forward Current	I_O	150	mA
Forward Steady-State Current	I_F	225	mA
Recurrent Peak Forward Current	i_f	600	mA
Peak Forward Surge Current (1.0s pulse)	I_{FSM}	500	mA
Peak Forward Surge Current (1.0 μ s pulse)	I_{FSM}	4.0	A
Power Dissipation	P_D	500	mW
Operating and Storage Junction Temperature	T_J, T_{stg}	-65 to +200	$^{\circ}\text{C}$

ELECTRICAL CHARACTERISTICS: ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

<u>SYMBOL</u>	<u>TEST CONDITIONS</u>	<u>MIN</u>	<u>MAX</u>	<u>UNITS</u>
I_R	$V_R=125\text{V}$		1.0	nA
I_R	$V_R=125\text{V}, T_A=125^{\circ}\text{C}$		500	nA
I_R	$V_R=125\text{V}, T_A=150^{\circ}\text{C}$		3.0	μA
I_R	$V_R=30\text{V}, T_A=125^{\circ}\text{C}$		300	nA
BV_R	$I_R=100\mu\text{A}$	150		V
V_F	$I_F=1.0\text{mA}$	0.54	0.69	V
V_F	$I_F=5.0\text{mA}$	0.62	0.77	V
V_F	$I_F=10\text{mA}$	0.65	0.80	V
V_F	$I_F=50\text{mA}$	0.75	0.88	V
V_F	$I_F=100\text{mA}$	0.79	0.92	V
V_F	$I_F=200\text{mA}$	0.83	1.0	V
C_T	$V_R=0, f=1.0\text{MHz}$		8.0	pF
t_{rr}	$V_R=3.5\text{V}, I_F=10\text{mA}, R_L=1.0\text{k}\Omega$		3.0	μs

JEDEC DO-35 CASE - MECHANICAL OUTLINE

DIMENSIONS				
SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.018	0.022	0.46	0.56
B	0.120	0.200	3.05	5.08
C	0.060	0.090	1.52	2.29
D	1.000	-	25.40	-

DO-35 (REV: R0)

R1

Marking Code: C1N3595

R1

Central[™]
Semiconductor Corp.

145 Adams Ave., Hauppauge, NY 11788 USA
Phone (631) 435-1110 FAX (631) 435-1824

Manufacturers of World Class Discrete Semiconductors
www.centrasemi.com